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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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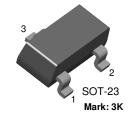




MMBTH34

NPN General Purpose Amplifier

- This device is designed for common-emitter low noise amplifier and mixer applications with collector currents in the 100mA to 20mA range to 300MHz, and low frequency drift common-base VHF oscillator applications with high output levels for driving FET mixers.
- Sourced from process 47.
- See MPSH11 for characteristics.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	4.0	V
I _C	Collector current - Continuous	50	mA
T _J , T _{stg}	Junction and Storage Temperature	-55 ~ +150	°C

Electrical Characteristics T_{C} =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Characte	Off Characteristics					
V _{(BR)CEO}	Collector-Emitter Sustaining Voltage *	$I_C = 1.0 \text{mA}, I_B = 0$	30			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	40			
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	4.0			VV
I _{CBO}	Collector Cutoff Current	$V_{CB} = 30V, I_{E} = 0$			50	nA
On Characte	On Characteristics					
h _{FE}	DC Current Gain	$I_C = 20 \text{mA}, V_{CE} = 2 \text{V}$	15			
Small Signal Characteristics						
f _T	Current Gain Bandwidth Product	I _C = 15mA, V _{CE} = 10V, f = 100MHz	500			MHz

^{*} Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

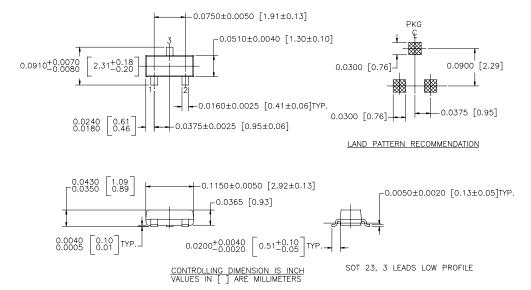
Thermal Characteristics TA=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	225	mW
	Derate above 25°C	1.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	556	°C/W

^{*} Device mounted on FR-4 PCB 1.6" × 1.6" × 0.06"

Package Dimensions

SOT-23



NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

Dimensions in Millimeters

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Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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